

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,953,730 B2
DATED : October 11, 2005
INVENTOR(S) : Ahn et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page,

Item 56, **References Cited**, U.S. PATENT DOCUMENTS, delete

"Forbes et al." and insert -- Ahn et al. --; delete "428/765" and insert -- 428/698 --.

OTHER PUBLICATIONS,

"Shin, Chang. H. et al." reference, delete "Fabriation" and insert -- Fabrication --.

"Aarik, Jaan, et al.," reference, delete "doposition" and insert -- deposition -- .

"De Flaviis, Franco, et al.," reference, delete "Micorwave" and insert -- Microwave --.

"Kim, Yongjo, et al.," reference, delete "micorwave" and insert -- microwave --.

"Molodyk, A.A., et al.," reference, after "(2000)," delete "),".

"Shin, Chang H., et al.," reference, delete "Fabriation" and insert -- Fabrication --.

"Takemoto, J.H., et al.," reference, delete "Superconductng" and insert
-- Superconducting --.

"Yamaguchi, Takeshi, et al.," reference, delete "Fabricated" and insert
-- Fabricated --.

"Zhu, W., et al.," reference, delete "Tranport" and insert -- Transport --.

"Chambers, J J., et al.," reference, delete "yltrium" and insert -- yttrium --.

"Kukli, K, et al.," reference, delete "porperties" and insert -- properties --.

"Kukli, K, et al.," (second occurrence), reference, delete "5598" and insert
-- 5698 --.

"Lee, S.J., et al.," reference, delete "Devicea" and insert -- Devices --.

"Lee, Jung-Hyoung, et al.," reference, delete "Meetings." and insert -- Meeting, --.

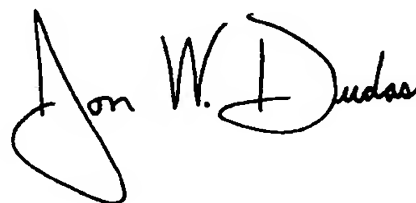
"Poveshchenko, V P., et al.," reference, delete "phas" and insert -- phase --.

Column 10,

Line 64, after "comprising" delete ";" and insert -- : --.

Signed and Sealed this

Twenty-first Day of March, 2006



JON W. DUDAS

Director of the United States Patent and Trademark Office